



# 150V 4.0m N-Ch Power MOSFET

## Features

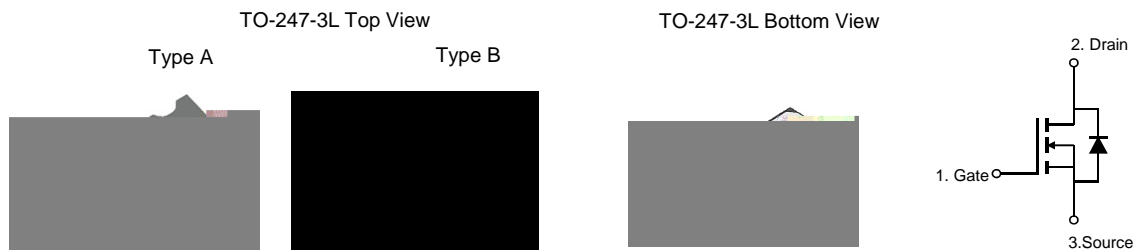
- Ultra-low  $R_{DS(ON)}$
- Low Gate Charge
- 100% UIS Tested, 100%  $R_g$  Tested
- Pb-free Lead Plating
- Halogen-free and RoHS-compliant

## Product Summary

Parameter	Value	Unit
$V_{DS}$	150	V
$V_{GS(th)_Typ}$	3.2	V
	203	A
	4.0	m

## Applications

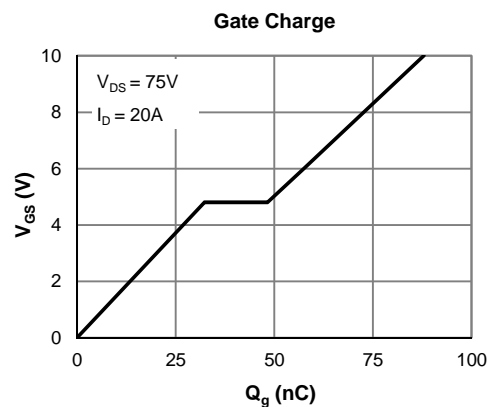
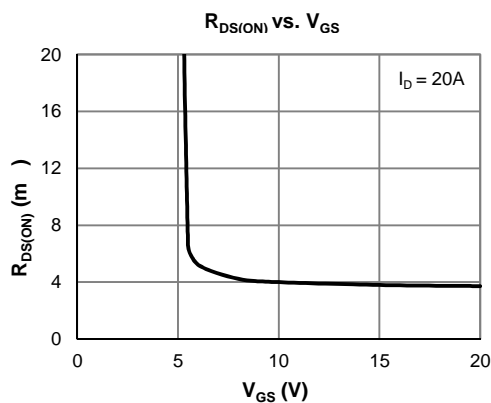
- Power Management in Telecom., Industrial Automation, CE
- Current Switching in DC/DC & AC/DC (SR) Sub-systems
- Motor Driving in Power Tool, E-vehicle, Robotics



	Package	# of Pins	Marking	MSL	$T_J$ (°C)	Media	Quantity (pcs)
JMSH1504AS-U	TO-247-3L	3	SH1504A	N/A	-55 to 150	Tube	30

## Absolute Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
	$V_{DS}$		V
	$V_{GS}$		V
Pulsed Drain Current <sup>(2)</sup>	$I_{DM}$	630	A
Avalanche Current <sup>(3)</sup>	$I_{AS}$	77	A
Avalanche Energy <sup>(3)</sup>	$E_{AS}$	889	mJ
Power Dissipation <sup>(4)</sup>	$P_D$	$T_C = 25^\circ\text{C}$	417
		$T_C = 100^\circ\text{C}$	167
Junction & Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	°C



### Electrical Characteristics (@ $T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions				
<b>STATIC PARAMETERS</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 250\text{ A}, V_{GS} = 0\text{ V}$				
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 120\text{ V}, V_{GS} = 0\text{ V}$ $T_J = 55^\circ\text{C}$				
Gate-Body Leakage Current	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$				
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\text{ A}$				
Static Drain-Source ON-Resistance]	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 20\text{ A}$				
Forward Transconductance	$g_{FS}$	$V_{DS} = 5\text{ V}, I_D = 20\text{ A}$				
Diode Forward Voltage	$V_{SD}$	$I_S = 1\text{ A}, V_{GS} = 0\text{ V}$				
Diode Continuous Current	$I_S$	$T_C = 25^\circ\text{C}$				
<b>DYNAMIC PARAMETERS <sup>(5)</sup></b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0\text{ V}, V_{DS} = 75\text{ V}, f = 1\text{ MHz}$				
Output Capacitance	$C_{oss}$				772	pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{GS} = 0\text{ V}, V_{DS} = 0\text{ V}, f = 1\text{ MHz}$			6.7	pF
Gate Resistance	$R_g$				2.4	
<b>SWITCHING PARAMETERS <sup>(5)</sup></b>						
	$Q_g(10\text{ V})$	$Q_g$	$V_{GS} = 0\text{ to }10\text{ V}$ $V_{DS} = 75\text{ V}, I_D = 20\text{ A}$		88	nC
	$Q_g(6.0\text{ V})$	$Q_g$			57	nC
		$Q_{gs}$			32	nC
		$Q_{gd}$			16	nC
		$t_{D(on)}$			48	ns
		$t_r$	$V_{GS} = 10\text{ V}, V_{DS} = 75\text{ V}$		90	ns
Turn-Off Delay Time	$t_{D(off)}$	$R_L = 3.75\ \Omega, R_{GEN} = 6\ \Omega$			94	ns
Turn-Off Fall Time	$t_f$				60	ns
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = 15\text{ A}, di_F/dt = 100\text{ A}/\text{s}$			122	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$	$I_F = 15\text{ A}, di_F/dt = 100\text{ A}/\text{s}$			279	nC

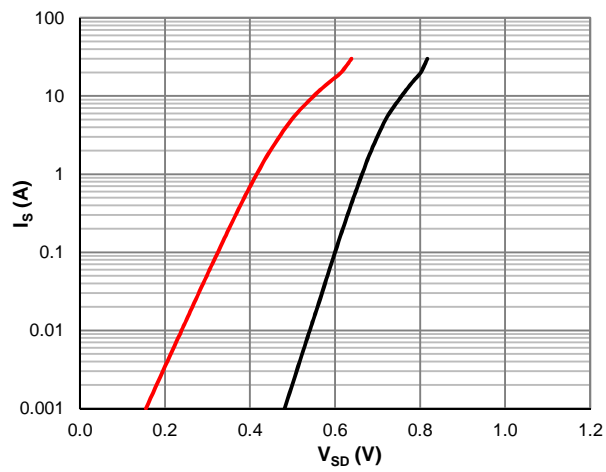
### Thermal Performance

Parameter	Symbol	Typ.	Max.	Unit
Thermal Resistance, Junction-to-Ambient	$R_{JA}$	40	48	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{JC}$	0.25	0.30	$^\circ\text{C}/\text{W}$

#### Notes:

1. Computed continuous current assumes the condition of  $T_{J,Max}$  while the actual continuous current depends on the thermal & electro-mechanical application board design.
2. This single-pulse measurement was taken under  $T_{J,Max} = 150^\circ\text{C}$ .
3. This single-pulse measurement was taken under the following condition [ $L = 300\ \text{H}, V_{GS} = 10\text{ V}, V_{DS} = 75\text{ V}$ ] while its value is limited by  $T_{J,Max} = 150^\circ\text{C}$ .
4. The power dissipation  $P_D$  is based on  $T_{J,Max} = 150^\circ\text{C}$ .
5. This value is guaranteed by design hence it is not included in the production test.

Typical Electrical & Thermal Characteristics





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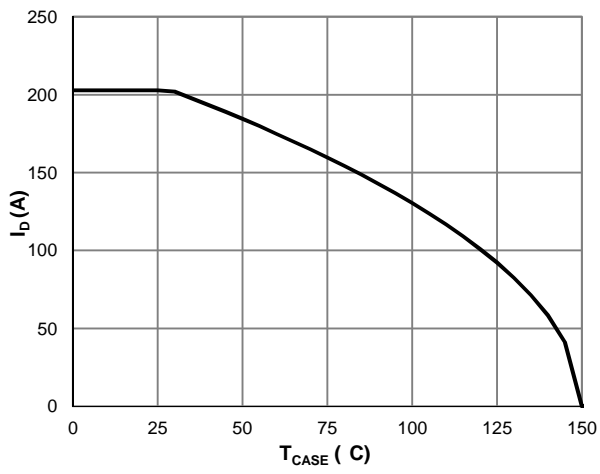


Figure 7: Current De-rating

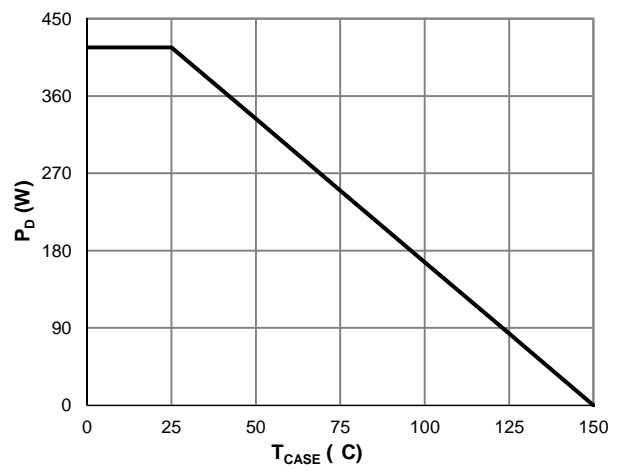
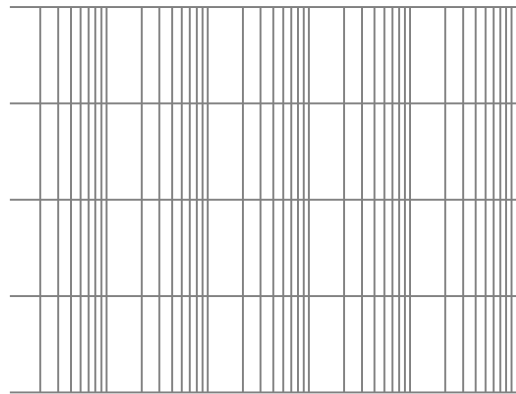


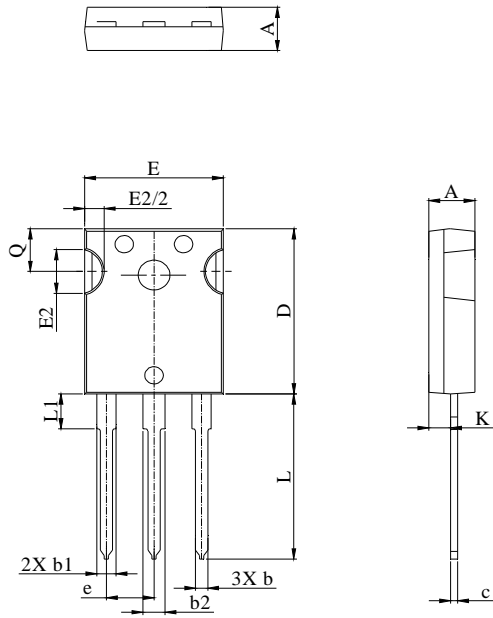
Figure 8: Power De-rating





TO-247-3L Package Information

Type\_A Package Outline



DIM.	MILLIMETER		
	MIN.	NOM.	MAX.
A	4.80	5.02	5.21
b	1.00	1.20	1.40
b1	1.90	2.00	2.39
b2	2.87	3.00	3.22
c	0.41	0.60	0.79
D	20.80	21.00	21.20
E	15.50	15.94	16.13